

# 2SJ508

Chopper Regulator, DC-DC Converter and Motor Drive Applications

- 4-V gate drive
- Low drain-source ON resistance :  $R_{DS(ON)} = 1.34 \Omega$  (typ.)
- High forward transfer admittance :  $|Y_{fs}| = 0.7 S$  (typ.)
- Low leakage current :  $I_{DSS} = -100 \mu A$  (max) ( $V_{DS} = -100 V$ )
- Enhancement mode :  $V_{th} = -0.8$  to  $-2.0 V$  ( $V_{DS} = -10 V, I_D = -1 mA$ )

### Absolute Maximum Ratings (Ta = 25°C)

| Characteristics                              |                | Symbol    | Rating     | Unit |
|--|----------------|-----------|------------|------|
| Drain-source voltage                         |                | $V_{DSS}$ | -100       | V    |
| Drain-gate voltage ( $R_{GS} = 20 k\Omega$ ) |                | $V_{DGR}$ | -100       | V    |
| Gate-source voltage                          |                | $V_{GSS}$ | $\pm 20$   | V    |
| Drain current                                | DC (Note 1)    | $I_D$     | -1         | A    |
|  | Pulse (Note 1) | $I_{DP}$  | -3         | A    |
| Drain power dissipation                      |                | $P_D$     | 0.5        | W    |
| Drain power dissipation (Note 2)             |                | $P_D$     | 1.5        | W    |
| Single pulse avalanche energy (Note 3)       |                | $E_{AS}$  | 136.5      | mJ   |
| Avalanche current                            |                | $I_{AR}$  | -1         | A    |
| Repetitive avalanche energy (Note 4)         |                | $E_{AR}$  | 0.05       | mJ   |
| Channel temperature                          |                | $T_{ch}$  | 150        | °C   |
| Storage temperature range                    |                | $T_{stg}$ | -55 to 150 | °C   |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

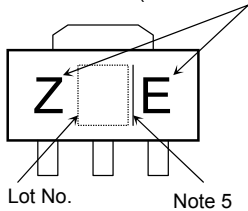
### Thermal Characteristics

| Characteristics                        | Symbol         | Max | Unit   |
|--|----------------|-----|--------|
| Thermal resistance, channel to ambient | $R_{th(ch-a)}$ | 250 | °C / W |

- Note 1: Ensure that the channel temperature does not exceed 150°C.
- Note 2: Mounted on a ceramic substrate (25.4 mm × 25.4 mm × 0.8 mm)
- Note 3:  $V_{DD} = -50 V, T_{ch} = 25^\circ C$  (initial),  $L = 168 mH, R_G = 25 \Omega, I_{AR} = -1 A$
- Note 4: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

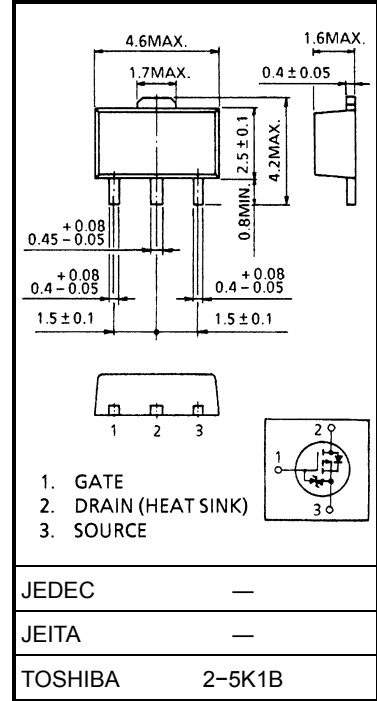
### Marking



- Note 5: A line to the right of a Lot No. identifies the indication of product Labels.  
 Without a line:  $[[Pb]]/INCLUDES > MCV$   
 With a line:  $[[G]]/RoHS COMPATIBLE$  or  $[[G]]/RoHS [[Pb]]$

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Unit: mm



Weight: 0.05 g (typ.)

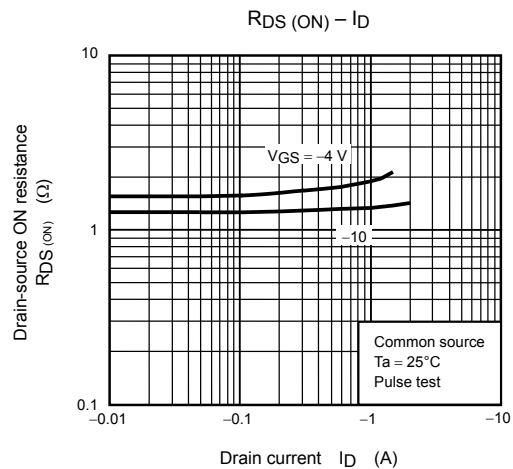
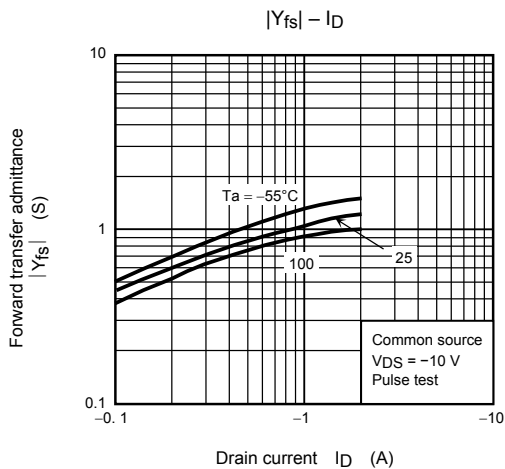
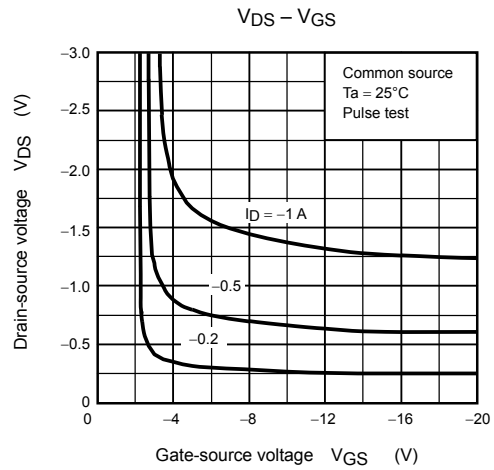
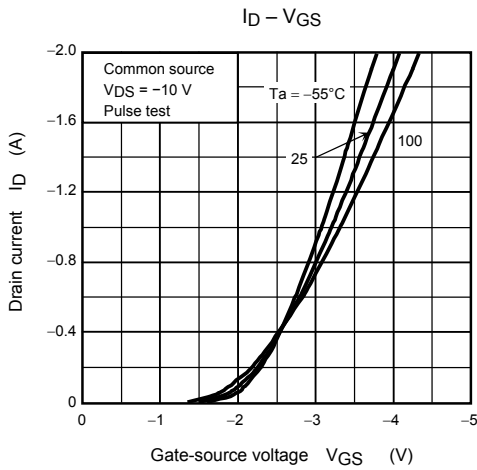
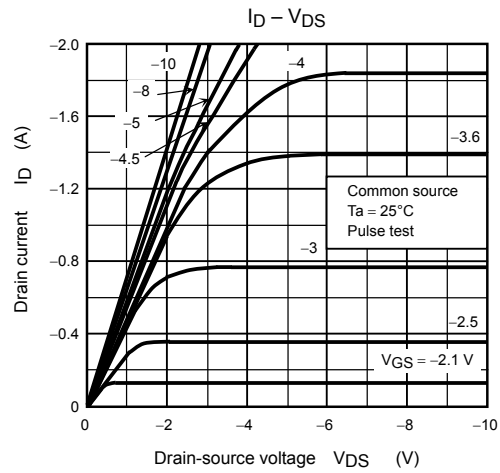
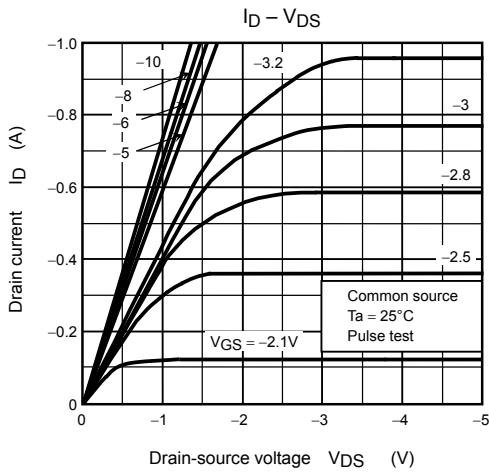
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| JEDEC   | —      |
| JEITA   | —      |
| TOSHIBA | 2-5K1B |

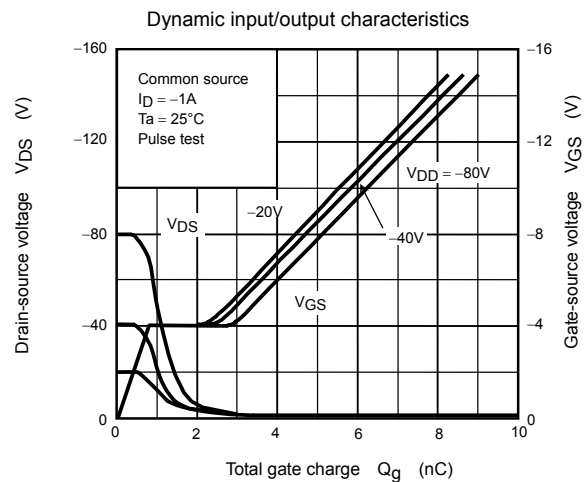
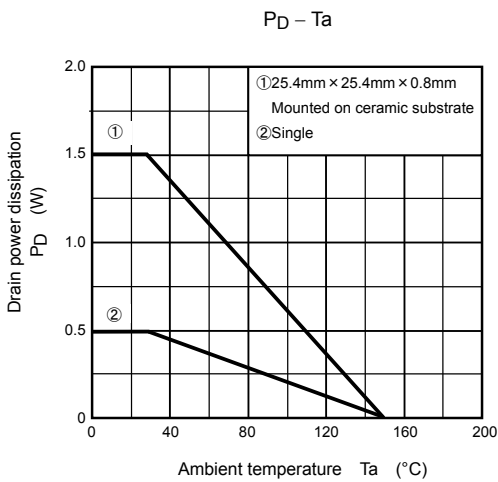
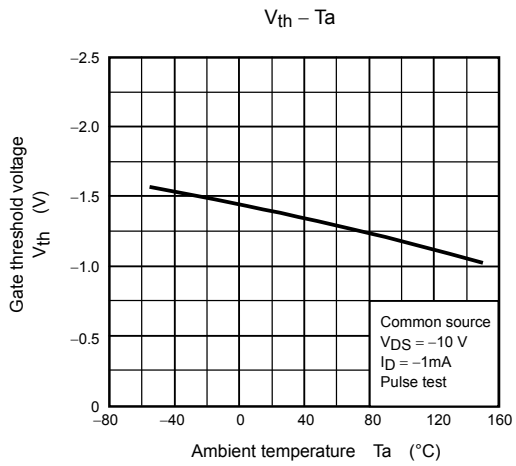
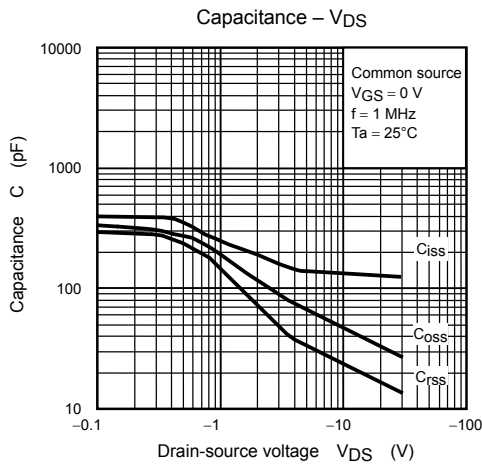
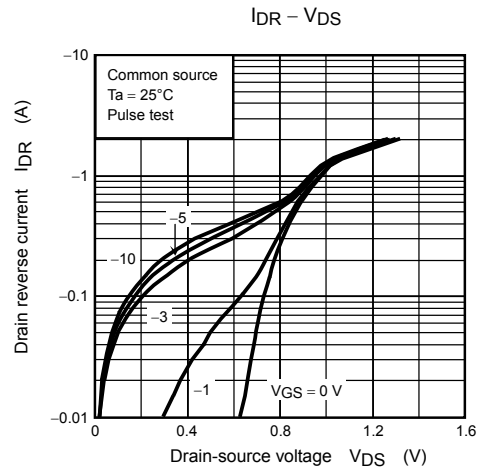
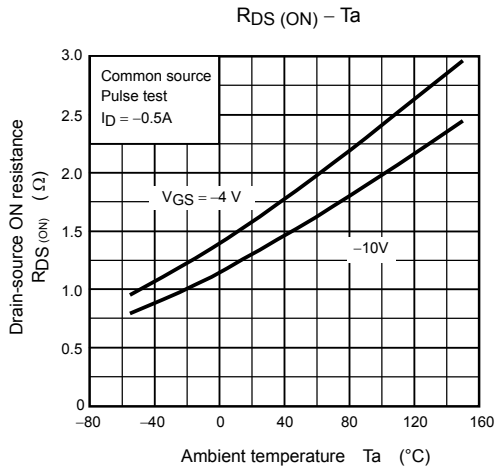
## Electrical Characteristics (Ta = 25°C)

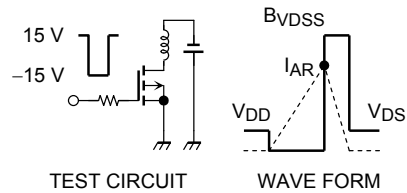
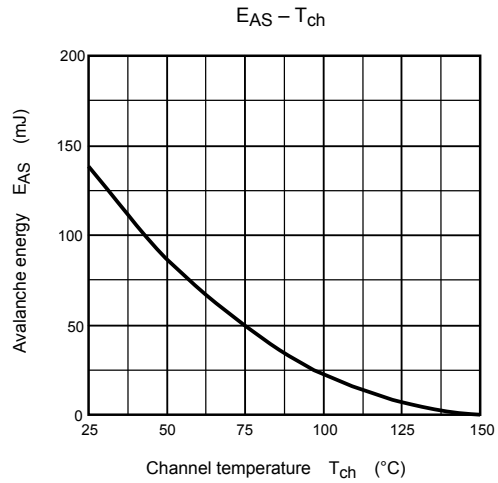
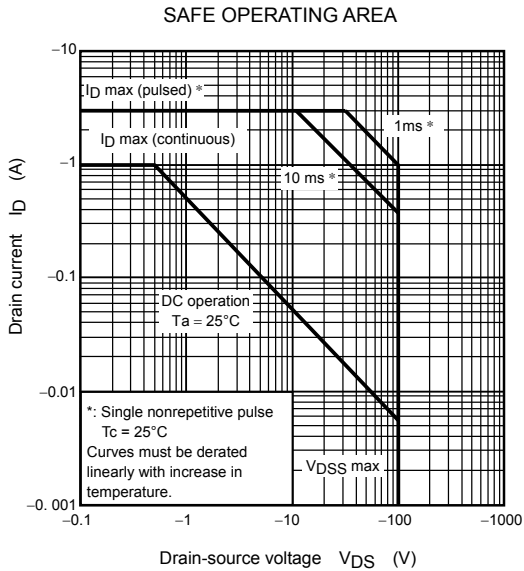
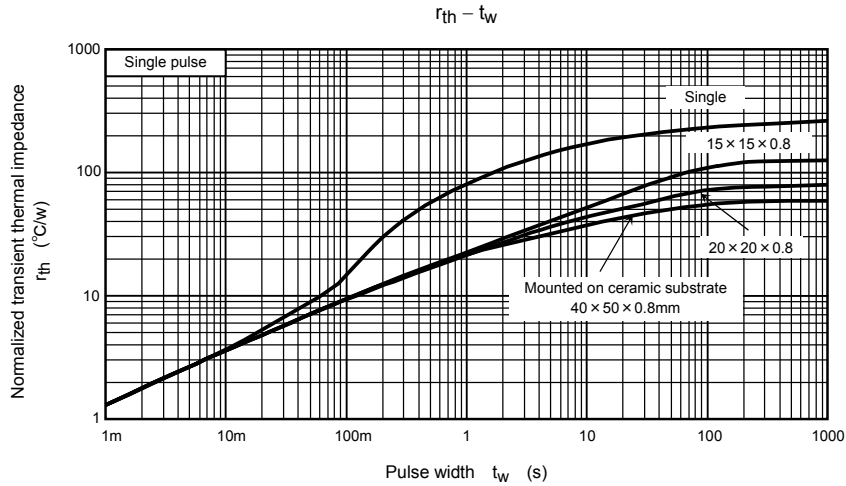
| Characteristics                                 |               | Symbol         | Test Condition  | Min  | Typ. | Max      | Unit          |
|---|---------------|----------------|---|------|------|----------|---------------|
| Gate leakage current                            |               | $I_{GSS}$      | $V_{GS} = \pm 16\text{ V}, V_{DS} = 0\text{ V}$   | —    | —    | $\pm 10$ | $\mu\text{A}$ |
| Drain cut-off current                           |               | $I_{DSS}$      | $V_{DS} = -100\text{ V}, V_{GS} = 0\text{ V}$   | —    | —    | -100     | $\mu\text{A}$ |
| Drain-source breakdown voltage                  |               | $V_{(BR) DSS}$ | $I_D = -10\text{ mA}, V_{GS} = 0\text{ V}$  | -100 | —    | —        | V             |
| Gate threshold voltage                          |               | $V_{th}$       | $V_{DS} = -10\text{ V}, I_D = -1\text{ mA}$   | -0.8 | —    | -2.0     | V             |
| Drain-source ON resistance                      |               | $R_{DS(ON)}$   | $V_{GS} = -4\text{ V}, I_D = -0.5\text{ A}$   | —    | 1.68 | 2.5      | $\Omega$      |
|   |               |                | $V_{GS} = -10\text{ V}, I_D = -0.5\text{ A}$  | —    | 1.34 | 1.9      |               |
| Forward transfer admittance                     |               | $ Y_{fs} $     | $V_{DS} = -10\text{ V}, I_D = -0.5\text{ A}$  | 0.3  | 0.7  | —        | S             |
| Input capacitance                               |               | $C_{iss}$      | $V_{DS} = -10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$  | —    | 135  | —        | pF            |
| Reverse transfer capacitance                    |               | $C_{rss}$      |   | —    | 22   | —        |               |
| Output capacitance                              |               | $C_{oss}$      |   | —    | 48   | —        |               |
| Switching time                                  | Rise time     | $t_r$          | <p><math>V_{GS} = 0\text{ V}</math><br/><math>V_{GS} = -10\text{ V}</math><br/><math>I_D = -0.5\text{ A}</math><br/><math>V_{OUT}</math><br/><math>R_L = 100\Omega</math><br/><math>V_{DD} = -50\text{ V}</math><br/>Duty <math>\leq 1\%</math>, <math>t_w = 10\mu\text{s}</math></p> | —    | 20   | —        | ns            |
|   | Turn-on time  | $t_{on}$       |   | —    | 32   | —        |               |
|   | Fall time     | $t_f$          |   | —    | 25   | —        |               |
|   | Turn-off time | $t_{off}$      |   | —    | 130  | —        |               |
| Total gate charge (Gate-source plus gate-drain) |               | $Q_g$          | $V_{DD} \approx -80\text{ V}, V_{GS} = -10\text{ V}, I_D = -1\text{ A}$   | —    | 6.3  | —        | nC            |
| Gate-source charge                              |               | $Q_{gs}$       |   | —    | 4.1  | —        |               |
| Gate-drain ("miller") charge                    |               | $Q_{gd}$       |   | —    | 2.2  | —        |               |

## Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics                           | Symbol    | Test Condition                              | Min | Typ. | Max | Unit |
|---|-----------|---|-----|------|-----|------|
| Continuous drain reverse current (Note 1) | $I_{DR}$  | —   | —   | —    | -1  | A    |
| Pulse drain reverse current (Note 1)      | $I_{DRP}$ | —   | —   | —    | -3  | A    |
| Forward voltage (diode)                   | $V_{DSF}$ | $I_{DR} = -1\text{ A}, V_{GS} = 0\text{ V}$ | —   | —    | 1.5 | V    |
| Reverse recovery time                     | $t_{rr}$  | $I_{DR} = -1\text{ A}, V_{GS} = 0\text{ V}$ | —   | 90   | —   | ns   |
| Reverse recovery charge                   | $Q_{rr}$  | $dI_{DR} / dt = 50\text{ A} / \mu\text{s}$  | —   | 180  | —   | nC   |







$$R_G = 25 \Omega$$

$$V_{DD} = -50 \text{ V}, L = 168 \text{ mH}$$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left( \frac{BVDSS}{BVDSS - V_{DD}} \right)$$

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